Naoyuki TAKAHASHI, Takato NAKAMURA, Satoshi NONAKA,
Applicant or Patentee: Hiromi YAGI, Yoicui SHINRIKI, Katsumi TAMANUKI Attorney's
Serial or Patent No.: Docket No.:
Filed or Issued: Concurrently
For: CRYSTAL THIN FILM AND PRODUCTION METHOD THEREFOR
VERIFIED STATEMENT (DECLARATION) CLAIMING SMALL ENTITY STATUS
(37 CFR 1.9(f) and 1.27(c)) - SMALL BUSINESS CONCERN
I hereby declare that I am
[] the owner of the small business concern identified below;
[x] an official of the small business concern empowered to act on behalf of the concern identified below;
NAME OF CONCERN Humo Laboratory, Ltd.
ADDRESS OF CONCERN 19-11, Nishiogikita 5-chome, Suginami-ku, Tokyo, JAPAN
I hereby declare that the above-identified small business concern qualifies as a small business concern as
defined in 12 CFR 121.3-18, and reproduced in 37 CFR 1.9(d), for purposes of paying reduced fees under
section 41(a) and (b) of Title 35, United States Code, in that the number of employees of the concern, including
those of its affiliates, does not exceed 500 persons. For purposes of this statement, (1) the number of employees
of the business concern is the average over the fiscal year of the concern of the persons employed on a full-time,
part-time or temporary basis during each of the pay periods of the fiscal year, and (2) concerns are affiliates of
each other either directly or indirectly, one concern controls or has the power to control the other, or a third
party or parties controls or has the power to control both.
I hereby declare that rights under contract or law have been conveyed to and remain with the small business
concern identified above with regard to the invention, entitled CRYSTAL THIN FILM AND PRODUCTION
by inventor(s) Naoyuki TAKAHASHI, Takato NAKAMURA, METHOD THEREFOR
described in Satoshi NONAKA, Hiromi YAGI, Yoichi SHINRIKI AND
the specification filed herewith Katsumi TAMANUKI
[] application serial no, filed
[] patent no, issued
If the rights held by the above-identified small business concern are not exclusive, each individual, concern or
organization having rights to the invention is listed below* and no rights to the invention are held by any
person, other than the inventor, who could not qualify as an independent inventor under 37 CFR 1.9(c) or by
any concern which would not qualify as a small business concern under 37 CFR 1.9(d) or a nonprofit
organization under 37 CFR 1.9(e). *NOTE: Separate verified statements are required from each named person,
concern or organization having rights to the invention averring to their status as small entities. (37 CFR 1.27) NAME
ADDRESS
I acknowledge the duty to file, in this application or patent, notification of any change in status resulting in loss of antitlement to small antity status micros a south of the instance of a status resulting in loss
of entitlement to small entity status prior to paying, or at the time of paying, the earliest of the issue fee or any
maintenance fee due after the date on which status as a small entity is no longer appropriate. (37 CFR 1.28(b)) I hereby declare that all statements made herein of my own knowledge are true and that all statements made on
information and belief are believed to be true; and further that these statements were made with the knowledge
that willful false statements and the like so made are punishable by fine or imprisonment, or both, under section
1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of
the application, any patent issuing thereon, or any patent to which this verified statement is directed.
the application, any patent issuing dieteon, of any patent to which this vertiled statement is directed.
NAME OF PERSON SIGNING Yoichi SHINRIKI
TITLE OF PERSON OTHER THAN OWNER President
ADDRESS OF PERSON SIGNING 16-1-303, Sakae-cho 1-chome, Tachikawa-shi, Tokyo

DATE December 29, 2000

JAPAN

SIGNATURE_DC2-DOCS1-105114

Naoyu	. TAKAHASHI, Takato NAKAMURA,	Sa shi NONAKA,
Applicant or Patentee: Hiromi	YAGI, Yoichi SHINRIKI, Katsu	mi TAMANUKI Attorney's
Serial or Patent No.:		Docket No.:
Filed or Issued: Concurrent1		
	D PRODUCTION METHOD THEREFOR	
VERIFIED STATEMEI (37 CFR 1	NT (DECLARATION) CLAIMING (1.9(f) and 1.27(b)) - INDEPENDENT	SMALL ENTITY STATUS
As below named inventor, I hereb	y declare that I qualify as an indep	endent inventor as defined in 37 CFR
1.9(c) for purposes of paying reduc	ed fees under section 41(a) and (b)	of Title 35. United States Code to the
Patent and Trademark Office with re	egard to the invention entitled CRYS	STAL THIN FILM AND PRODUCTION
described in	METH	HOD THEREFOR
(x) the specification filed herewit	h	
[] application serial no.	, filedi	<u> </u>
[] patent no, issued	i	:
I have not assigned, granted, conve	yed or licensed and am under no obl	igation under contract or law to assign
grant, convey or license, any rights	in the invention to any person who ca	ould not be classified as an independent
inventor under 37 CFR 1.9(c) if tha	t person had made the invention, or t	to any concern which would not qualify
as a small business concern under 3	7 CFR 1.9(d) or a nonprofit organiza	tion under 37 CFR 1.9(e).
Each person, concern or organization	on to which I have assigned, granted	, conveyed, or licensed or am under an
obligation under contract or law to a	issign, grant, convey or license any ri	ghts in the invention is listed below:
[] no such person, concern or or		
X persons, concerns or organiza		
NOIE: Separate verified states	ments are required from each named	person, concern or organization having
rights to the invention avering to the	eir status as small entities. (37 CFR	1.27)
FULL NAME Humo Laborate		
	kita 5-chome, Suginami-k	
I sobreviled to the duty to Ele in the	L BUSINESS CONCERN []]	NONPROFIT ORGANIZATION
of entitlement to small entity status	is application or patent, notification (of any changes in status resulting in loss
maintenance fee due after the date of	prior to paying, or at the time or pay	ying, the earliest of the issue fee or any longer appropriate. (37 CFR 1.28(b))
I hereby declare that all statements	made herein of my own knowledge	are true and that all statements made on
information and belief are believed	to be true: and further that these star	tements were made with the knowledge
that willful false statements and the	like so made are punishable by fine	or imprisonment, or both, under section
1001 of Title 18 of the United State	s Code, and that such willful false st	atements may jeopardize the validity of
the application, any patent issuing the	hereon, or any patent to which this ve	erified statement is directed.
	,, F	•
NT	101	
Naoyuki TAKAHASHI	Takato NAKAMURA	Satoshi NONAKA
NAME OF INVENTOR	NAME OF INVENTOR	NAME OF INVENTOR
Praguki Takapushi	Takets Nakamur	Satodi noraka
SIGNATURE OF INVENTOR	SIGNATURE OF INVENTOR	SIGNATURE OF INVENTOR
29 December, 2000	29 December, 2000	29 December, 2000
DATE	DATE	DATE
· · ·		•
Hiromi YAGI	Yoichi SHINRIKI	Katsumi TAMANUKI
NAME OF INVENTOR	NAME OF INVENTOR	NAME OF INVENTOR
Hironi hagi	V Sprinnilei	B. artonich
SIGNATURE OF INVENTOR	SIGNATURE OF INVENTOR	SIGNATURE OF INVENTOR
29 December, 2000	29 December, 2000	29 December, 2000
DATE	DATE	DATE
DC2-DOCS1-105110		

	RESPONDEN ADDRESS
stated below next to my name, and that I believe I am the	esidence, post office address and citizenship are a
listed below) or an original, first and joint inventor (if pi	ural names are listed below) of the subject matte
which is claimed and for which a nateu	is sought on the invention entitle
CRYSTAL THIN FILM AND PRODUCTION M	ETHOD THEREFOR
	the specification of which
[24] is attached hereto.	
was filed onas Application No	
and was amended on [if applicable].	
[] was filed under the Patent Cooperation Treaty on Serial No, the United States of America bein	t designated
I hereby state that I have reviewed and understand to	be contents of the above identified specification
including the claims, as amended by any amendment referr	ed to above.
I acknowledge the duty to disclose to the Patent and Tra	demark Office all information known to me to be
uniterial to patentability as defined in Title 37, Code of Fede	ral Regulations, §1.56(a).
I hereby claim foreign priority benefits under Title 35, Unfor patent, utility model, design or inventor's certificate lists	ited States Code, 9119 of any foreign application(s
application(s) for patent, utility model, design or inventor	s certificate having a filing date before that of the
application(s) on which priority is claimed:	a mag date before that of the
Prior Foreign Application(s)	Priority Claimed
Number Country Date Filed	
2000-270300 JAPAN September I hereby appoint the following attorneys to prosecute the	is application and to the second all builties
Patent and Trademark Office connected therewith: Georg	is application and to transact all business in the
(Reg.No. 20,586), Robert J. Frank (Reg. No. 19,112), Gabo	r J. Kelemen (Reg. No. 21,016), Robert Kinberg
(Reg. No. 26,924), John W. Schneller (Reg. No. 26,031), As	liley J. Wells (Reg. No. 29,847), Allen Wood (Reg.
No. 28,134), P.O. Box 34385, Washington, D.C. 20043-999	8, Telephone: (202) 962-4800, Telefax: (202) 962-
8300. Address all correspondence to VENABLE, BAETJ 34385, Washington, D.C. 20043-9998.	ER, HOWARD & CIVILETTI, LLP, P.O. Box
The undersigned hereby authorizes the U.S. attorneys na	ned herein to accept and follow instructions from
the undersigned's assignee, if any, and/or, if the undersi	gued is not a resident of the United States, the
undersigned's domestic attorney, patent attorney or patent a	gent, as to any action to be taken in the Patent and
Trademark Office regarding this application without direct	communication between the U.S. attorneys and the
undersigned. In the event of a change in the person(s) attorneys named herein will be so notified by the undersigne	from whom instructions may be taken, the U.S.
I hereby declare that all statements made herein of my ow	i.
on information and belief are believed to be true; and fu	y with a leafer the time and that all statements wade
Immediate that the Letters are the Letters and the Letters are the Letters and Letters are the Letters and Letters are the Letters and Letters are the Letters	riller that these statements were made with the
knowledge that willful false statements and the like so made	rther that these statements were made with the
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validity of the application or any patent issued thereon. Signature: Tokshasha' Sole or First Joint Inventor: Naoyuki TAKAHASHI	rther that these statements were made with the are punishable by fine or imprisonment, or both, such willful false statements may jeopardize the
validity of the application or any patent issued thereon. Signature: North Tokohash'	rther that these statements were made with the are punishable by fine or imprisonment, or both, such willful false statements may jeopardize the Date: 29 December ,2000.
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Naoyuki TAKAHASHI et al.

Serial No. 09/767,154

Filed: January 23, 2001

For: CRYSTAL THIN FILM AND

PRODUCTION METHOD THEREFOR

Art Unit: 1765

Examiner: Matthew J. Song

Atty. Docket No. 31721-169084

Customer No.

26694

ATENT TRADEMARK OPEICE

STATEMENT OF HISASHI INOGUCHI

Assistant Commissioner of Patents and Trademarks Washington, D.C. 20231

Sir:

I, HISASHI INOGUCHI, sent a substitute specification to the law office of Venable for the subject application. I am the agent for the applicants in Japan.

I am conversant in both the Japanese and English languages.

The presentation of the substitute specification is to conform the specification to the drawings of the application filed in the U.S. and identified above. I further state that the substitute specification contains no new matter. In the application drawings the word "quartz" is used; please see Figure 6. However in translation of the Japanese language specification, the Japanese word for "quartz" may also refer to crystal. This is evidenced by comparing the terms on Figure 6 referring to quartz to the terms in the specification describing Figure 6 which refers to employs the word 'crystal' Example 2, at page 15 line 8 thereof.

Amorphous silicon dioxide and single crystalline silicon dioxide (quartz) can be

represented by the same chemical formula "SiO2". However, single crystalline silicon dioxide

has completely different physical characteristics from that of amorphous silicon dioxide.

Amorphous silicon dioxide has only insulating properties and amorphous silicon dioxide thin

film is often used as an insulation film for semiconductor devices. On the other hand single

crystalline silicon dioxide has resonance and piezo electric characteristics.

Accordingly, it appears that the changes presented in the substitute specification are not

only supported by the case as originally filed, and thus do no constitute new matter, but also will

enrich the art by the disclosure as presented therein.

I further declare that all statements herein are made with the knowledge that willful false

statements may jeopardize the validity of any U.S. patent issuing on the U.S. application and/or

may result in fine(s) and/or imprisonment.

Date: December 1/11 2,0012

DC2#419602

Hisashi Inoguchi

2